

# INCHANGE SEMICONDUCTOR

BDT30F/AF/BF/CF/DF

# **isc** Silicon PNP Power Transistors

### DESCRIPTION

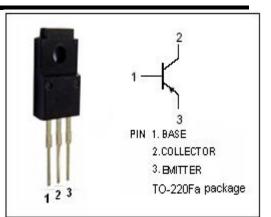
- DC Current Gain -h<sub>FE</sub> = 40(Min)@ I<sub>C</sub>= -0.4A
- Collector-Emitter Sustaining Voltage-
  - : V<sub>CEO(SUS)</sub> = -40V(Min)- BDT30F; -60V(Min)- BDT30AF -80V(Min)- BDT30BF; -100V(Min)- BDT30CF -120V(Min)- BDT30DF
- Complement to Type BDT29F/AF/BF/CF/DF
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

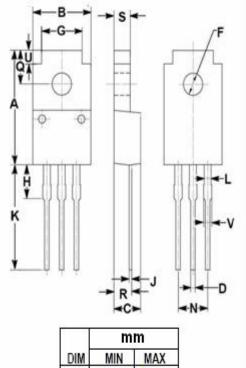
#### APPLICATIONS

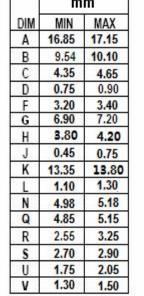
• Designed for use in audio output stages , general purpose amplifier and high speed switching applications

SYMBOL PARAMETER VALUE UN							
OTMODE		VALUE	UNIT				
V <sub>сво</sub>	Collector-Base Voltage	BDT30F	-80	V			
		BDT30AF	-100				
		BDT30BF	-120				
		BDT30CF	-140				
		BDT30DF	-160				
V <sub>CEO</sub>	Collector-Emitter Voltage	BDT30F	-40	V			
		BDT30AF	-60				
		BDT30BF	-80				
		BDT30CF	-100				
		BDT30DF	-120				
$V_{\text{EBO}}$	Emitter-Base Voltage	-5	V				
lc	Collector Current-Contin	-1	А				
I <sub>СМ</sub>	Collector Current-Peak	-3	А				
I <sub>B</sub>	Base Current	-0.4	А				
Pc	Collector Power Dissipation $T_c=25^{\circ}C$	19	W				
Tj	Junction Temperature	150	°C				
T <sub>stg</sub>	Storage Ttemperature R	-65~150	°C				

#### ABSOLUTE MAXIMUM RATINGS(Ta=25℃)







## THERMAL CHARACTERISTICS

SYMBOL	PARAMETER	MAX	UNIT
R <sub>th j-c</sub>	Thermal Resistance, Junction to Case	9.17	°C/W
R <sub>th j-a</sub>	Thermal Resistance, Junction to Ambient	55	°C/W

isc website: <u>www.iscsemi.com</u>

## <sup>1</sup> *isc* & *iscsemi* is registered trademark



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### **ELECTRICAL CHARACTERISTICS**

#### $T_{\text{c}}\text{=}25^{\circ}\!\!\!^{\circ}\!\!^{\circ}$ unless otherwise specified

SYMBOL	PARAMETER		CONDITIONS	MIN	TYP.	MAX	UNIT
V <sub>CEO(SUS)</sub>	Collector-Emitter Sustaining Voltage	BDT30F		-40			
		BDT30AF		-60			
		BDT30BF	I <sub>C</sub> = -30mA; I <sub>B</sub> = 0	-80			V
		BDT30CF		-100			
		BDT30DF		-120			
V <sub>CE(sat)</sub>	Collector-Emitter Saturation Voltage		I <sub>C</sub> = -1A; I <sub>B</sub> = -0.125A			-0.7	V
V <sub>BE(on)</sub>	Base-Emitter On Voltage		I <sub>C</sub> = -1A ; V <sub>CE</sub> = -4V			-1.3	V
I <sub>CES</sub>	Collector Cutoff Current		V <sub>CE</sub> = V <sub>CEOmax</sub> ; V <sub>BE</sub> = 0			-0.2	mA
	Collector Cutoff Current	BDT30F/AF	V <sub>CE</sub> = -30V; I <sub>B</sub> = 0				mA
I <sub>CEO</sub>		BDT30BF/CF	V <sub>CE</sub> = -60V; I <sub>B</sub> = 0			-0.1	
		BDT30DF	V <sub>CE</sub> = -90V; I <sub>B</sub> = 0				
I <sub>EBO</sub>	Emitter Cutoff Current		V <sub>EB</sub> = -5V; I <sub>C</sub> = 0			-0.2	mA
h <sub>FE-1</sub>	DC Current Gain		Ic= -0.2A ; Vce= -4V	40			
h <sub>FE-2</sub>	DC Current Gain		I <sub>C</sub> = -1A ; V <sub>CE</sub> = -4V	15		75	
f⊤	Current-Gain—Bandwidth Product		I <sub>C</sub> = -0.2A ; V <sub>CE</sub> = -10V	3			MHz
Switching T	ïmes		·				

ton	Turn-On Time		0.3	μ <b>S</b>
toff	Turn-Off Time	I <sub>C</sub> = -1.0A; I <sub>B1</sub> = -I <sub>B2</sub> = -0.1A	1.0	μs

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